

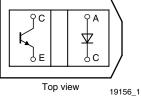
Vishay Semiconductors

RoHS

COMPLIANT

Reflective Optical Sensor with Transistor Output





DESCRIPTION

The TCRT5000 and TCRT5000L are reflective sensors which include an infrared emitter and phototransistor in a leaded package which blocks visible light. The package includes two mounting clips. TCRT5000L is the long lead version.

FEATURES

- Package type: leaded
- Detector type: phototransistor
- Dimensions (L x W x H in mm): 10.2 x 5.8 x 7
- · Peak operating distance: 2.5 mm
- Operating range within > 20 % relative collector current: 0.2 mm to 15 mm
- Typical output current under test: I_C = 1 mA
- Daylight blocking filter
- Emitter wavelength: 950 nm
- · Lead (Pb)-free soldering released
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

APPLICATIONS

- · Position sensor for shaft encoder
- Detection of reflective material such as paper, IBM cards, magnetic tapes etc.
- · Limit switch for mechanical motions in VCR
- · General purpose wherever the space is limited

PRODUCT SUMMARY					
PART NUMBER	ART NUMBER DISTANCE FOR MAXIMUM CTR _{rel} ⁽¹⁾ (mm)		TYPICAL OUTPUT CURRENT UNDER TEST ⁽²⁾ (mA)	DAYLIGHT BLOCKING FILTER INTEGRATED	
TCRT5000	2.5	0.2 to 15	1	Yes	
TCRT5000L	2.5	0.2 to 15	1	Yes	

Notes

⁽¹⁾ CTR: current transfere ratio, I_{out}/I_{in}

⁽²⁾ Conditions like in table basic charactristics/sensors

ORDERING INFORMATION

ORDERING CODE	PACKAGING	VOLUME ⁽¹⁾	REMARKS	
TCRT5000	Tube	MOQ: 4500 pcs, 50 pcs/tube	3.5 mm lead length	
TCRT5000L	Tube	MOQ: 2400 pcs, 48 pcs/tube	15 mm lead length	

Note

⁽¹⁾ MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾					
PARAMETER	TEST CONDITION	ION SYMBOL VALUE		UNIT	
INPUT (EMITTER)					
Reverse voltage		V _R	5	V	
Forward current		I _F	60	mA	
Forward surge current	$t_p \le 10 \ \mu s$	I _{FSM}	3	A	
Power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	Pv	100	mW	
Junction temperature		Tj	100	°C	

TCRT5000, TCRT5000L

Vishay Semiconductors

Reflective Optical Sensor with Transistor Output



ABSOLUTE MAXIMUM RATINGS ⁽¹⁾					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
OUTPUT (DETECTOR)					
Collector emitter voltage		V _{CEO}	70	V	
Emitter collector voltage		V _{ECO}	5	V	
Collector current		Ι _C	100	mA	
Power dissipation	$T_{amb} \le 55 \ ^{\circ}C$	Pv	100	mW	
Junction temperature		Tj	100	°C	
SENSOR					
Total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	P _{tot}	200	mW	
Ambient temperature range		T _{amb}	- 25 to + 85	°C	
Storage temperature range		T _{stg}	- 25 to + 100	°C	
Soldering temperature	2 mm from case, $t \leq$ 10 s	T _{sd}	260	°C	

Note

 $^{(1)}$ T_{amb} = 25 °C, unless otherwise specified

ABSOLUTE MAXIMUM RATINGS

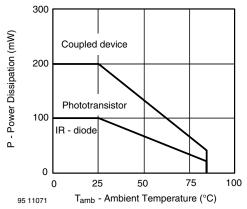


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS ⁽¹⁾						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT (EMITTER)						
Forward voltage	I _F = 60 mA	VF		1.25	1.5	V
Junction capacitance	V _R = 0 V, f = 1 MHz	Cj		17		pF
Radiant intensity	$I_F = 60 \text{ mA}, t_p = 20 \text{ ms}$	l _e			21	mW/sr
Peak wavelength	I _F = 100 mA	λ _P	940			nm
Virtual source diameter	Method: 63 % encircled energy	d		2.1		mm
OUTPUT (DETECTOR)						
Collector emitter voltage	$I_{\rm C} = 1 \rm{mA}$	V _{CEO}	70			V
Emitter collector voltage	I _e = 100 μA	V _{ECO}	7			V
Collector dark current	$V_{CE} = 20 \text{ V}, \text{ I}_{F} = 0 \text{ A}, \text{ E} = 0 \text{ Ix}$	I _{CEO}		10	200	nA
SENSOR						
Collector current	$V_{CE} = 5 V, I_F = 10 mA,$ D = 12 mm	I _C ^{(2) (3)}	0.5	1	2.1	mA
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 0.1 \text{ mA},$ D = 12 mm	V _{CEsat} ^{(2) (3)}			0.4	v

Note

 $^{(1)}$ T_{amb} = 25 °C, unless otherwise specified

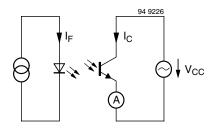
(2) See figure 3

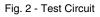
⁽³⁾ Test surface: mirror (Mfr. Spindler a. Hoyer, Part No. 340005)



TCRT5000, TCRT5000L

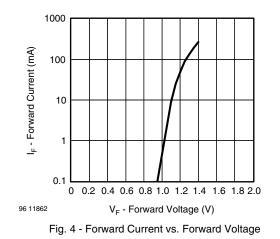
Reflective Optical Sensor with Transistor Output **Vishay Semiconductors**





BASIC CHARACTERISTICS

 T_{amb} = 25 °C, unless otherwise specified



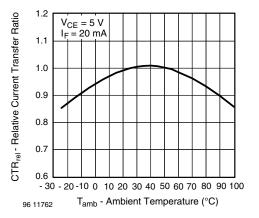


Fig. 5 - Relative Current Transfer Ratio vs. Ambient Temperature

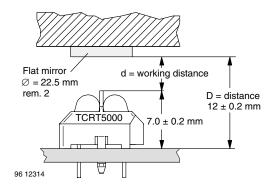
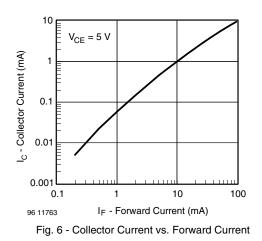


Fig. 3 - Test Circuit



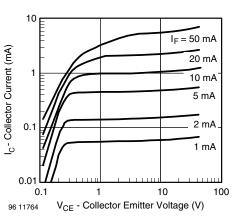


Fig. 7 - Collector Emitter Saturation Voltage vs. Collector Current

TCRT5000, TCRT5000L

Vishay Semiconductors

Reflective Optical Sensor with Transistor Output



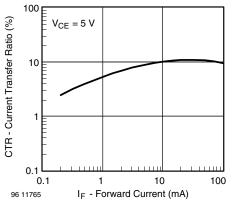


Fig. 8 - Current Transfer Ratio vs. Forward Current



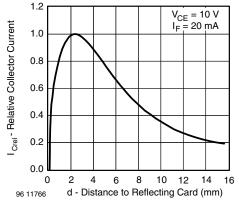
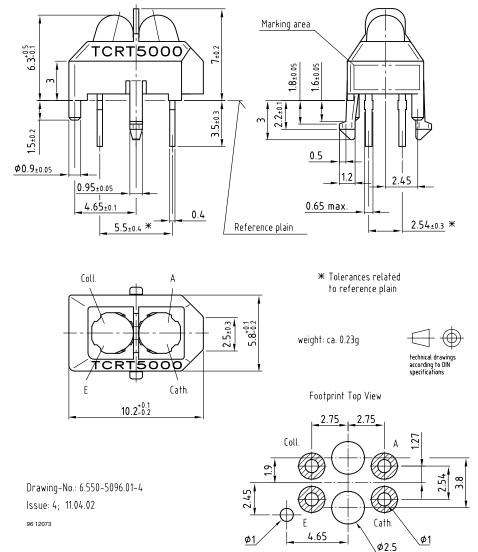


Fig. 9 - Relative Collector Current vs. Distance

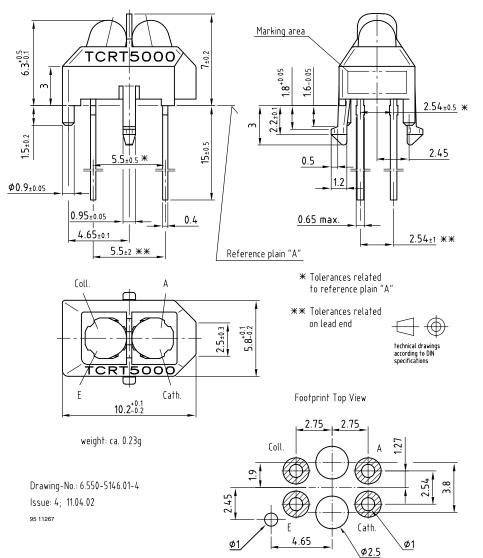


For technical questions, contact: sensorstechsupport@vishay.com



Reflective Optical Sensor with Transistor Output **Vishay Semiconductors**

PACKAGE DIMENSIONS in millimeters, TCRT5000L

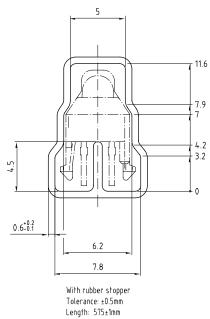


Vishay Semiconductors

Reflective Optical Sensor with Transistor Output

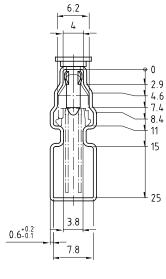


TUBE DIMENSIONS in millimeters, TCRT5000



Drawing-No.: 9.700-5139.01-4 Issue: 1; 10.05.00 20298

TUBE DIMENSIONS in millimeters, TCRT5000L



With stopper pins Tolerance: ±0.5mm Length: 575±1mm

Drawing-No.: 9.700-5178.01-4 Issue: 1; 25.02.00 20299



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.